

Lab 3

Cascode Amplifier

Part 1: Sizing Chart

Required Spec:

$A_v = g_m r_o$	50
g_m/I_D	10 S/A
Supply (V_{DD})	1.8 V
Quiescent (DC) output voltage	$V_{DD}/2 = 0.9\text{ V}$
Bias Current	20 μA

Analytic Calculations:

$$|A_v| \approx g_m r_o = \frac{2I_D}{V_{ov}} \times \frac{V_A}{I_D} = \frac{2V_A}{V_{ov}}$$

In Simulation $V_{ov} \neq \frac{2I_D}{g_m}$ all the time, Instead use $V^ = \frac{2I_D}{g_m}$*

$$|A_v| = \frac{2V_A}{V^*}$$

$$g_m = \frac{2I_D}{V_{ov}} \rightarrow \frac{g_m}{I_D} = \frac{2}{V_{ov}}$$

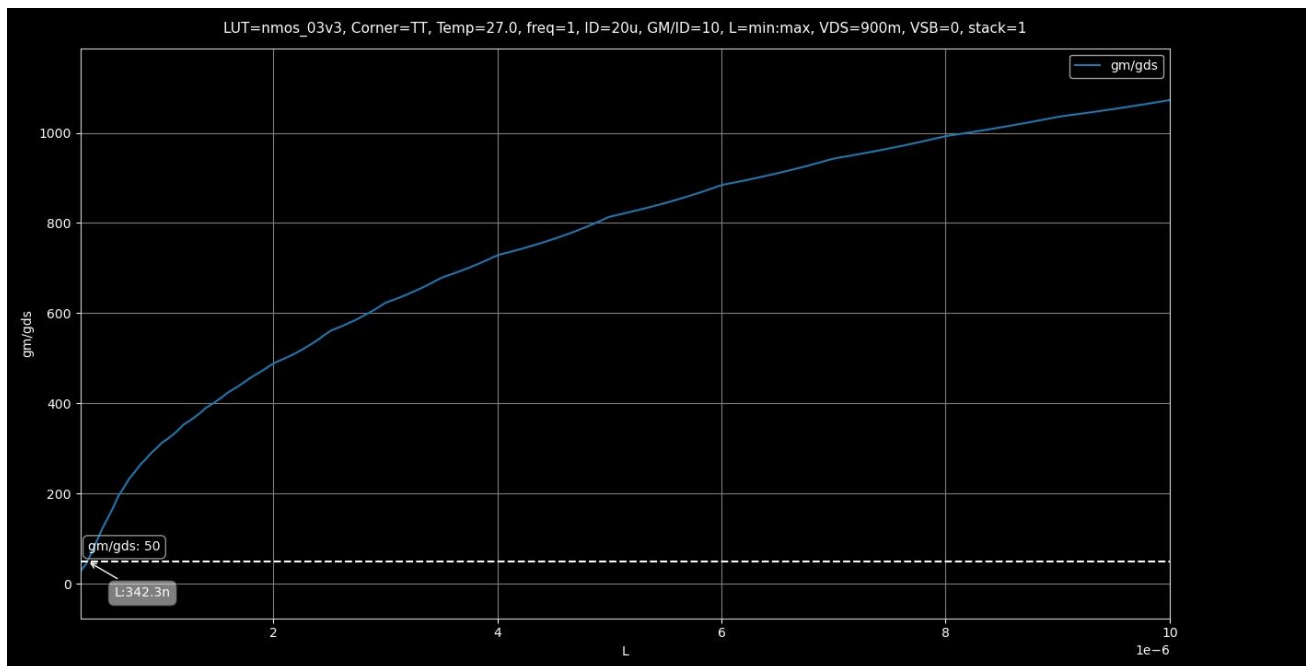


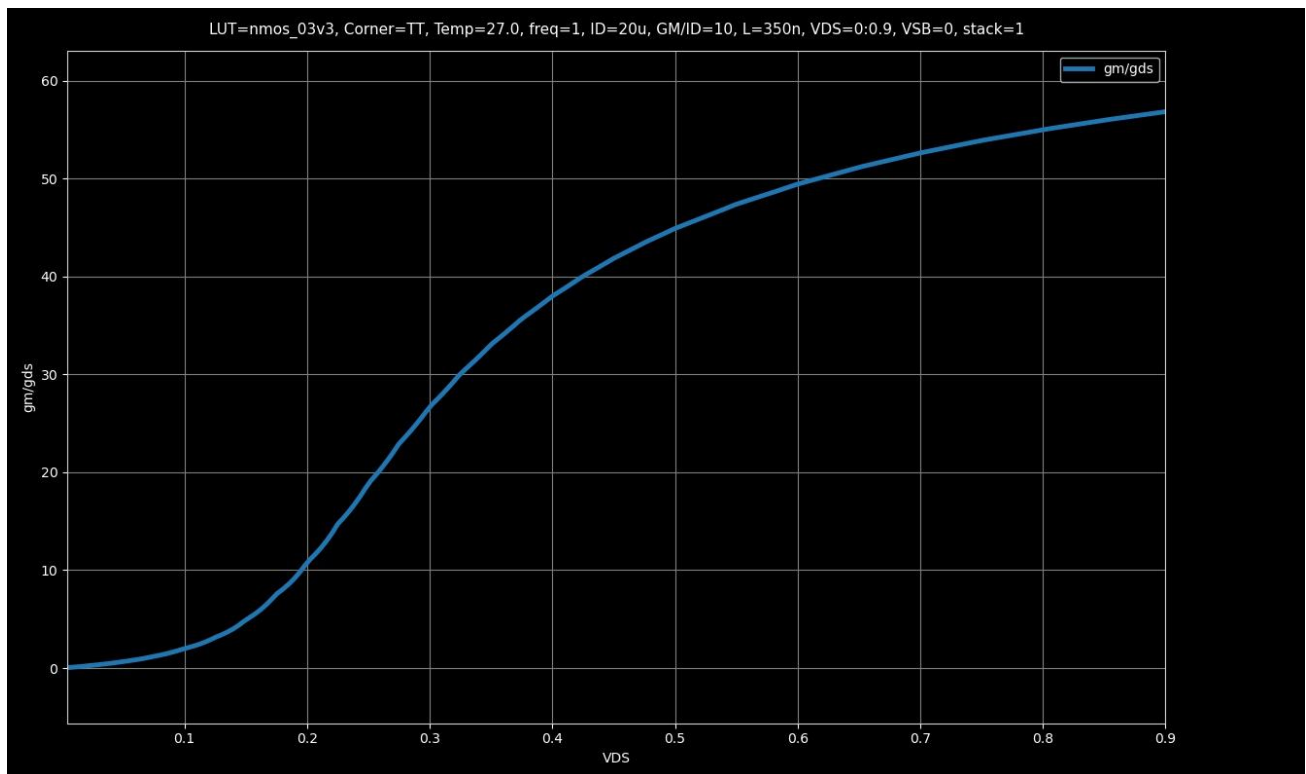
Figure 1 g_m/g_{ds} vs L

$L = 342.3\text{ nm} \rightarrow L \approx 350\text{ nm}$ to account for gain drops in simulation.

Figure 2 Remaining Parameters @ $L = 350\text{nm}$ 6) W using SA:

$$W = 3.5\mu\text{m}$$

7)

Figure 3 gm/gds vs VDS Graph

8) gm/gds will be slightly lower approximately equal to 41.83

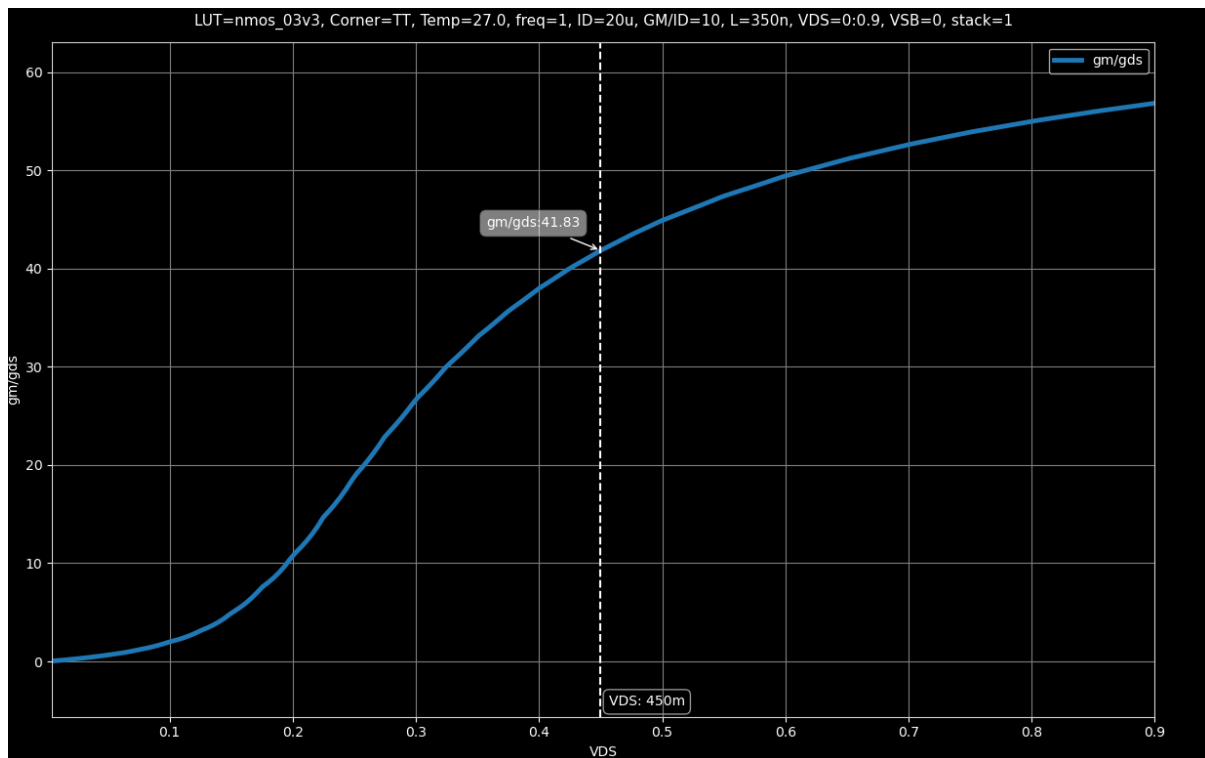


Figure 4 Expected gm/gds

Part 2: Cascode for Gain

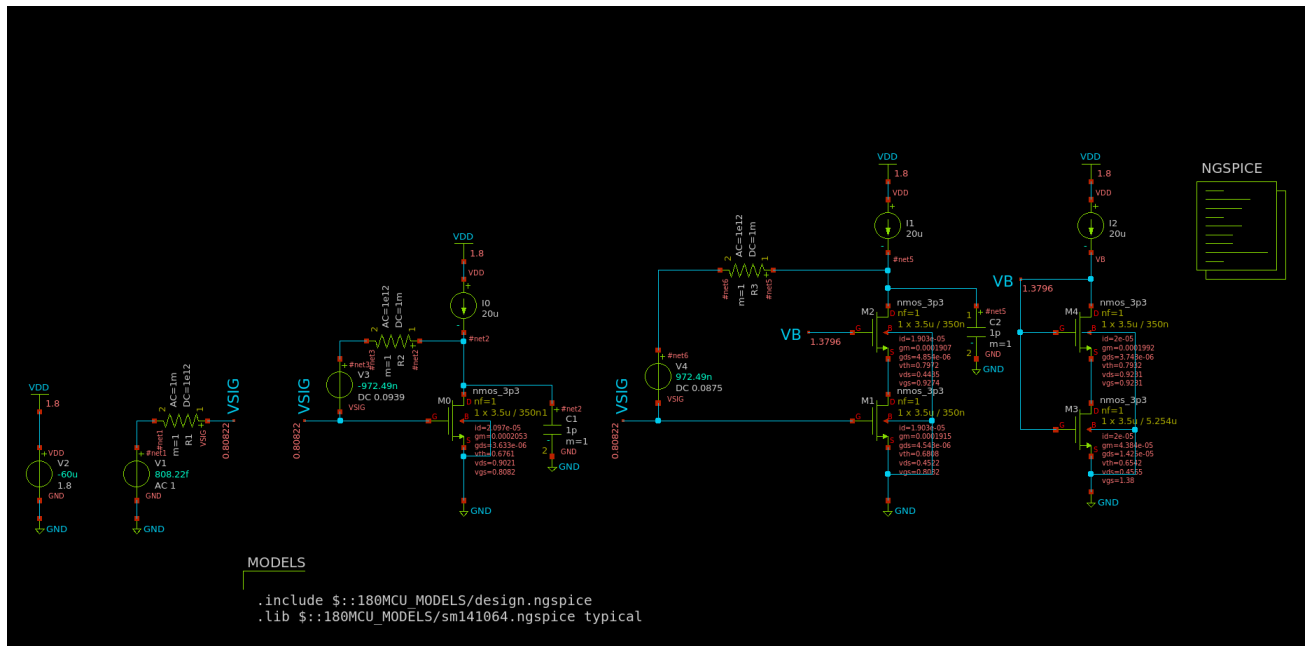


Figure 5 Testbench Schematic

$$V_3 \approx V_4 \approx 0.1mV$$

Finding VGS0 and VGS1 for V3 and V4 (ADT):

LUT

nmos_03v3

?

Corner

TT

All

?

Temp (°C)

27.0

All

?

Frequency

1

?

ID

20u

?

gm/ID

10

?

L

350n

?

VDS

0.9

?

VSb

0

?

Stack

1

?

Results:

	Name	TT-27.0
1	ID	20u
2	IG	N/A
3	L	350n
4	W	3.49u
5	VGS	806.1m
6	VDS	900m
7	VSb	0
8	gm/ID	9.909

LUT

nmos_03v3

?

Corner

TT

All

?

Temp (°C)

27.0

All

?

Frequency

1

?

ID

20u

?

gm/ID

10

?

L

350n

?

VDS

0.45

?

VSb

0

?

Stack

1

?

Results:

	Name	TT-27.0
1	ID	20u
2	IG	N/A
3	L	350n
4	W	3.59u
5	VGS	812.5m
6	VDS	450m
7	VSb	0
8	gm/ID	9.866

$$VGS_0 = 806.1mV \quad VGS_1 = 812.5m$$

$$V_{Bias} = VDC - VGS \rightarrow V_3 = 900m - 806.1m = 93.9mV, V_4 = 900m - 812.5m = 87.5mV$$

Calculating V_B :

$$V_B = V_{GS2} + V_{DS1}$$

We can get V_{GS2} using ADT by putting $V_{DS} = 0.45$ and accounting for body effect so $V_{SB} = 0.45$ and inputting the dimensions calculated previously.

ID	20u
W	3.5u
L	350n
VDS	0.45
VSB	0.45
Stack	1
Results:	
Name	TT-27.0
1 ID	20u
2 IG	N/A
3 L	350n
4 W	3.5u
5 VGS	927.7m
6 VDS	450m
7 VSB	450m
8 gm/ID	9.79
9 Vstar	204.3m
10 fT	6.72G

Figure 6 V_{GS2} using ADT

$$V_B = 927.7m + 450m = 1.377V$$

Getting L of M3:

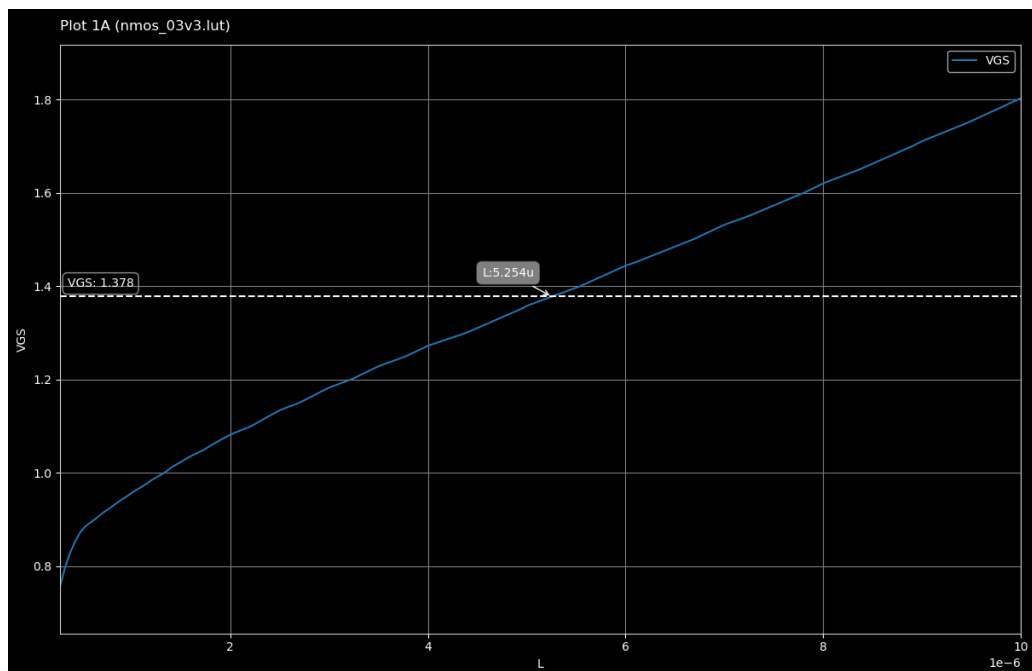


Figure 7 V_{GS} vs L (ADT) for M3

$$L_{required} = 5.254\mu m$$

DC Operating Point:

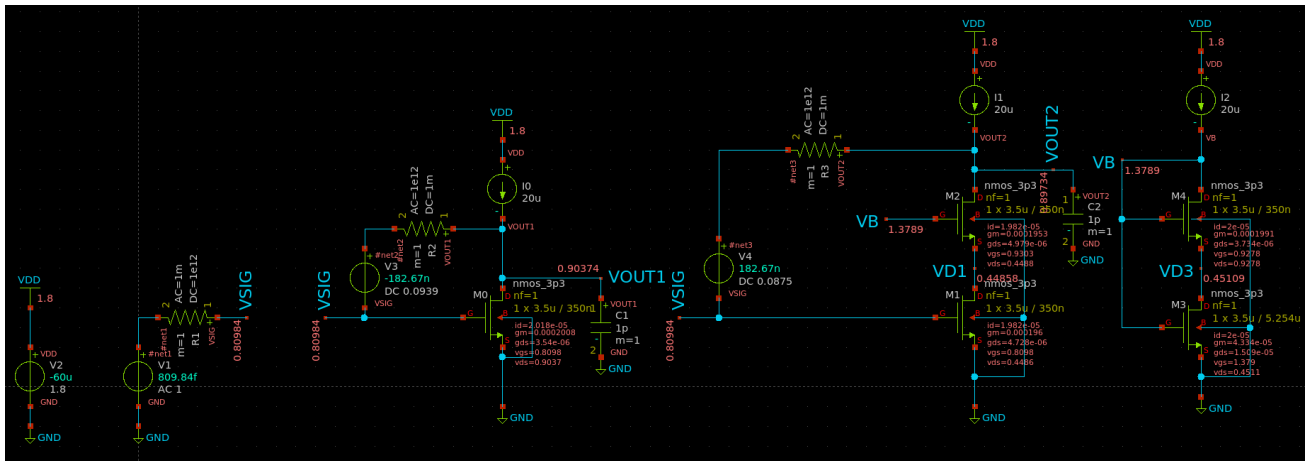


Figure 8 DC Voltages Annotated on Schematic

9) OP parameters for M0 to M4

To get these quickly I exported the results to a CSV and displayed the results here as follows:

	M0	M1	M2	M3	M4
cdb	-3.11E-16	-3.09E-16	-2.39E-16	-9.57E-15	-2.36E-16
cgd	1.65E-17	1.16E-17	1.49E-17	-5.63E-15	2.13E-17
cgs	-2.60E-15	-2.56E-15	-2.62E-15	-5.18E-14	-2.63E-15
csb	-4.66E-16	-4.61E-16	-3.56E-16	-1.25E-14	-3.54E-16
gds	3.72E-06	4.36E-06	4.82E-06	1.33E-05	3.76E-06
gm	2.09E-04	1.88E-04	1.87E-04	4.45E-05	1.99E-04
gmbs	5.99E-05	5.40E-05	4.13E-05	1.73E-05	4.38E-05
id	2.16E-05	1.84E-05	1.84E-05	2.00E-05	2.00E-05
vds	8.96E-01	4.60E-01	4.30E-01	4.63E-01	9.16E-01
vdsat	1.67E-01	1.60E-01	1.64E-01	5.59E-01	1.66E-01
vgs	8.02E-01	8.02E-01	9.19E-01	1.38E+00	9.16E-01
vth	6.67E-01	6.79E-01	7.92E-01	6.55E-01	7.86E-01

- **Check that all transistors operate in saturation.**

All Operate in saturation except for M3 operates in triode, The cascode configuration is meant to increase the length of the equivalent transistor that we can get from the series connection of the transistors, as the voltage of the middle point is too low for M3 to operate in saturation especially when M4 pulls it down to operate in saturation.

- **Do all transistors have the same v_{th} ? Why?**

M0, M1 and M3 have similar V_{th} as they are not affected much by body effect but M2 and M4 being cascode devices have a higher V_{th} than the others due to body effect.

- **What is the relation (\ll , $<$, $=$, $>$, \gg) between g_m and g_{ds} ?**

$g_m \gg$ (Much Greater Than) g_{ds} , except for M3 it's only greater than ($>$)

- **What is the relation (\ll , $<$, $=$, $>$, \gg) between g_m and g_{mb} ?**

$g_m >$ (Greater Than) g_{mb}

- **What is the relation (\ll , $<$, $=$, $>$, \gg) between c_{gs} and c_{gd} ?**

$C_{gs} \gg$ (Much Greater Than) C_{gd} except for M3 the ratio is about 9.2 so only almost much greater than it

- **What is the relation (\ll , $<$, $=$, $>$, \gg) between c_{sb} and c_{db} ?**

$C_{sb} >$ (Greater Than) c_{db}

AC Analysis:

Outputs:

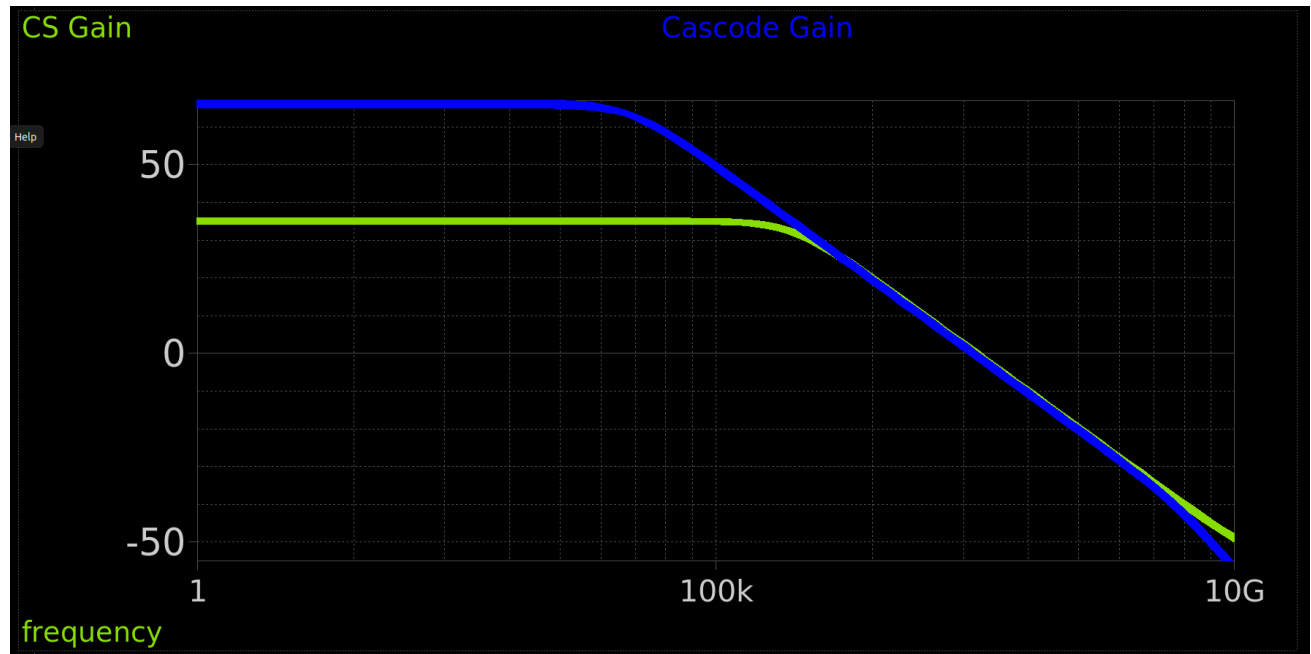


Figure 9 Bode Plots of both CS and Cascode Amplifiers

All Results:

	CS	Cascode
Gain (dB)	35.14	65.56
Gain	57.2	1.9 K
BW	523.3 KHz	16.98 KHz
GBW	29.936 MHz	32.338 MHz
UGF	30.134 MHz	32.371 MHz

Hand Analysis:

CS Amplifier:

$$DC\ Gain = |A_v| = gm * ro = \frac{gm}{gds} = \frac{209\mu}{3.72\mu} \approx \mathbf{56.182}$$

$$Gain\ in\ dB = 20Log(A_v) = 20Log(56.182) \approx \mathbf{35dB}$$

Bandwidth (Neglecting transistor Capacitances and current source resistance):

$$F_p = \frac{1}{\tau * 2\pi} = \frac{1}{2\pi * ro * C_L} = \frac{gds}{2\pi * C_L} = \frac{3.72\mu}{2\pi * 1p} = \mathbf{592.05\ KHz}$$

$$GBW = Gain * BW = 56.182 * 592.05\ K = \mathbf{33.263MHz}$$

$$Since\ this\ is\ a\ Single\ Pole\ System: \quad UGF = GBW = \mathbf{33.263MHz}$$

Cascode Amplifier:

$$R_{out} \approx ro_2(gm_2 + gmb_2)ro_1 = \frac{gm_2 + gmb_2}{gds_1 * gds_2} = \frac{187\mu + 41.3\mu}{4.36\mu * 4.82\mu} = \mathbf{10.86M\Omega}$$

$$DC\ Gain = |A_v| = Gm * R_{out} = gm_1 * R_{out} = 188\mu * 10.86M \approx \mathbf{2K}$$

$$Gain\ in\ dB = 20Log(A_v) = 20Log(2K) = \mathbf{66.2\ dB}$$

Bandwidth (Neglecting transistor Capacitances and current source resistance):

$$F_p = \frac{1}{\tau * 2\pi} = \frac{1}{2\pi * R_{out} * C_L} = \frac{1}{2\pi * 1p * 10.86M} = \mathbf{14.65\ KHz}$$

$$GBW = Gain * BW = 7K * 2.78K = \mathbf{29.31\ MHz}$$

$$Since\ this\ is\ a\ Single\ Pole\ System: \quad UGF = GBW = \mathbf{29.31MHz}$$

Comparison of Results:

	CS		Cascode	
	Simulation	Analytic	Simulation	Analytic
Gain (dB)	35.14	35	65.56	66.2
Gain	57.2	56.182	1.9 K	2 K
BW	523.3 KHz	592.05 KHz	16.98 KHz	14.65 KHz
GBW	29.936 MHz	33.263 MHz	32.338 MHz	29.31 MHz
UGF	30.134 MHz	33.263MHz	32.371 MHz	29.31 MHz

Comments:

- Simulation and Analytic Results are nearly identical! Whilst a bit far in the frequency calculations due to neglecting transistor capacitances
- Cascode amplifier has a much greater gain than the CS Amplifier. Due to the higher output resistance
- The Bandwidth of the Cascode Amplifier is much lesser than the CS Amplifier also due to the higher output resistance.
- This results in both amplifiers having nearly identical Gain-Bandwidth-Product as well as Unity Gain Frequency.

Part 3: Cascode for BW:

Calculating VRD:

$$V_{RD} = \frac{1.8}{2} = 0.9 \rightarrow R_D = \frac{0.9}{20\mu} = 45K\Omega$$

OP Point:

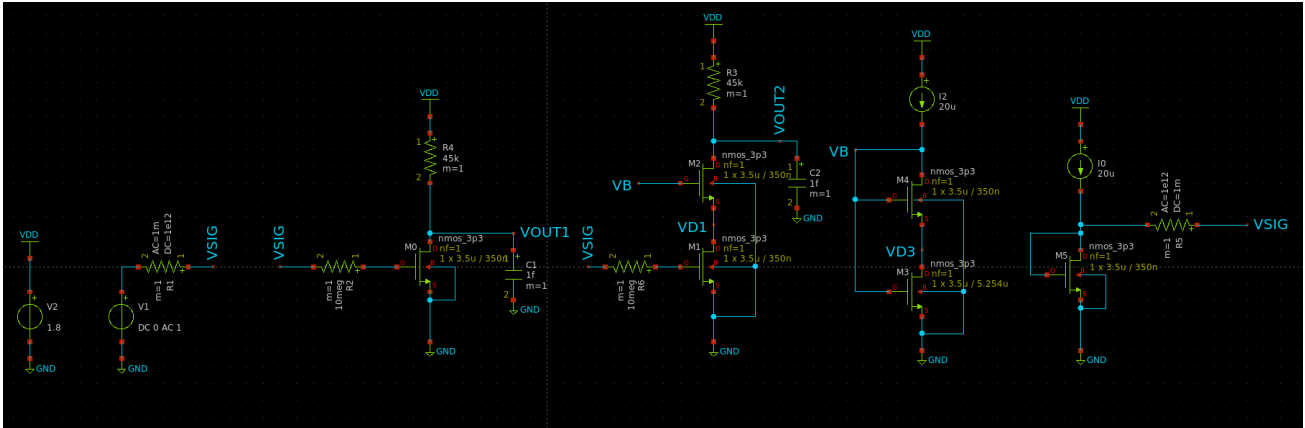


Figure 10 DC OP with Points Annotated

All Results:

	M0	M1	M2	M3	M4	M5
cdb	-3.08E-16	-3.10E-16	-2.39E-16	-9.64E-15	-2.37E-16	-3.08E-16
cgd	1.63E-17	1.15E-17	1.78E-17	-5.91E-15	2.13E-17	1.61E-17
cgs	-2.57E-15	-2.57E-15	-2.62E-15	-5.18E-14	-2.63E-15	-2.57E-15
csb	-4.62E-16	-4.62E-16	-3.56E-16	-1.26E-14	-3.55E-16	-4.62E-16
gds	3.57E-06	4.43E-06	4.41E-06	1.39E-05	3.75E-06	3.63E-06
gm	2.01E-04	1.89E-04	1.89E-04	4.41E-05	1.99E-04	1.99E-04
gmbs	5.77E-05	5.45E-05	4.19E-05	1.72E-05	4.39E-05	5.72E-05
id	2.03E-05	1.86E-05	1.86E-05	2.00E-05	2.00E-05	2.00E-05
vds	8.87E-01	4.58E-01	5.04E-01	4.59E-01	9.20E-01	8.07E-01
vdsat	1.63E-01	1.61E-01	1.64E-01	5.60E-01	1.66E-01	1.63E-01
vgs	8.07E-01	8.07E-01	9.21E-01	1.38E+00	9.20E-01	8.07E-01
vth	6.78E-01	6.82E-01	7.94E-01	6.54E-01	7.90E-01	6.79E-01

- **Check that all transistors operate in saturation.**

All Operate in saturation except for M3 operates in triode, The cascode configuration is meant to increase the length of the equivalent transistor that we can get from the series connection of the transistors, as the voltage of the middle point is too low for M3 to operate in saturation especially when M4 pulls it down to operate in saturation.

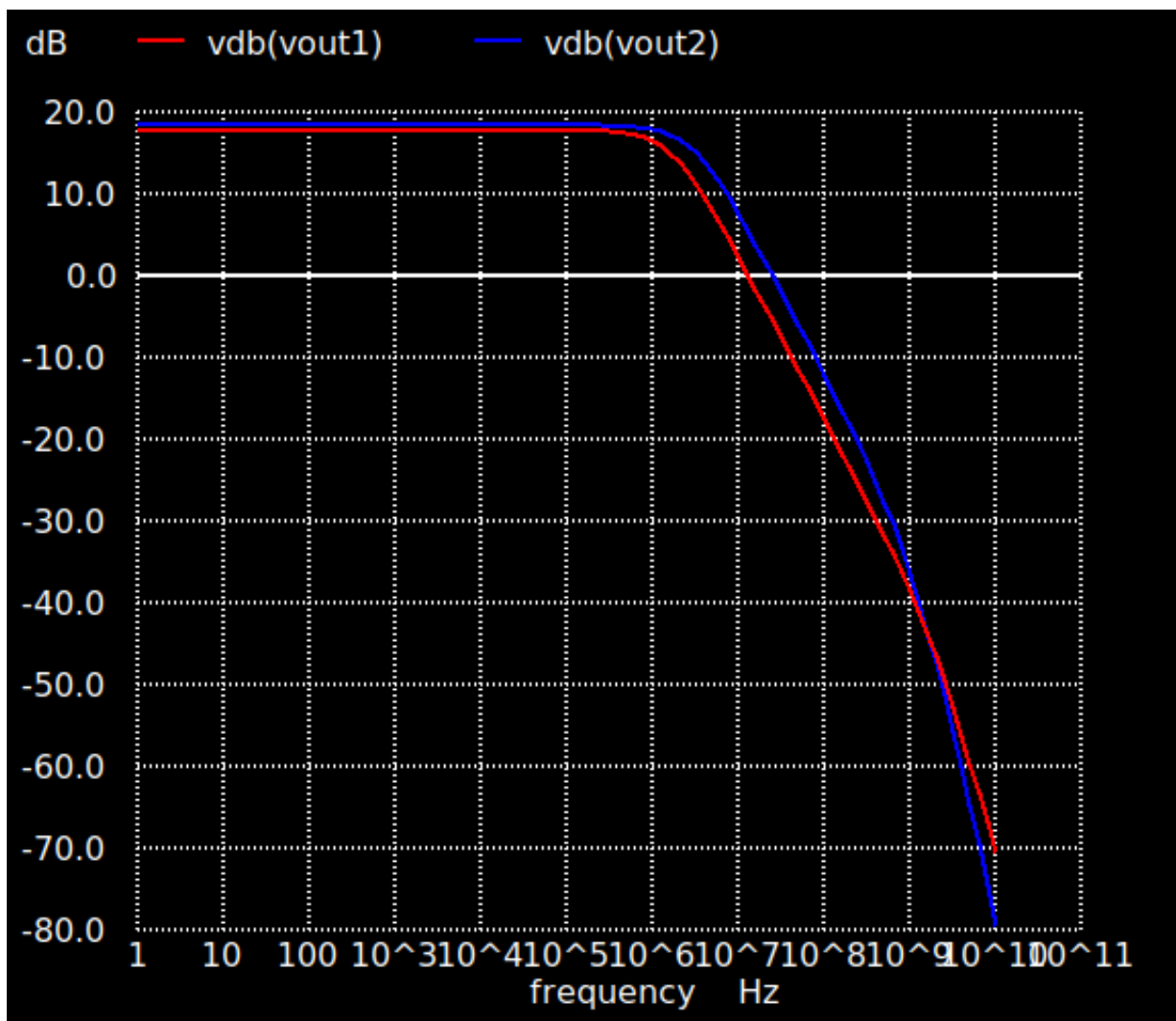
AC Analysis:

Figure 11 Bode Plot Blue: Cascode, Red: CS

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peak1          = 7.806966e+00
f3db1          = 1.695066e+06
ugf1           = 1.318210e+07
gbw1 = 1.323332e+07
peak2          = 8.332359e+00
f3db2          = 3.008278e+06
ugf2           = 2.486529e+07
gbw2 = 2.506605e+07

```

Figure 12 Simulation Values of DC Gain, BW, UGF, GBW (1 is CS and 2 is Cascode)

Hand Analysis:

CS Amplifier:

$$DC\ Gain = |A_v| = g_m * r_o // R_D = 201\mu * (280K // 45K) \approx \mathbf{7.792}$$

$$Gain\ in\ dB = 20\text{Log}(A_v) = 20\text{Log}(7.792) \approx \mathbf{17.83dB}$$

Bandwidth (Input Node is Dominant):

$$F_P = \frac{1}{\tau * 2\pi} = \frac{1}{2\pi * R_{sig} * (C_{gs} + (A_v + 1) * C_{gd})}$$

$$= \frac{1}{2\pi * 10M * (3.09f + (8.792) * 592.7a)} = \mathbf{1.917\ MHz}$$

$$GBW = Gain * BW = 7.792 * 1.917\ M = \mathbf{14.939MHz}$$

Since this is a Single Pole System: $UGF = GBW = \mathbf{14.939MHz}$

Cascode Amplifier:

$$R_{out} \approx R_D = \mathbf{45K\Omega}$$

$$DC\ Gain = |A_v| = G_m * R_{out} = g_{m1} * R_{out} = 189\mu * 45K \approx \mathbf{8.5}$$

$$Gain\ in\ dB = 20\text{Log}(A_v) = 20\text{Log}(8.5) = \mathbf{18.588\ dB}$$

Bandwidth (Input Node is Dominant):

$$R_{LFS} = \frac{1}{g_m} \left(1 + \frac{R_D}{r_{o2}} \right) = 6.34K\Omega, \quad F_P = \frac{1}{\tau * 2\pi} = \frac{1}{2\pi * R_{sig} * (C_{gs} + (g_{m1} * R_{LFS} + 1) * C_{gd})}$$

$$= \frac{1}{2\pi * 10M * (3.5f + (2.2) * 745.4a)} = \mathbf{3.0965\ MHz}$$

$$GBW = Gain * BW = 7.792 * 1.917\ M = \mathbf{26.32MHz}$$

Since this is a Single Pole System: $UGF = GBW = \mathbf{26.32\ MHz}$

Comparison of the Results:

	CS		Cascode	
	Simulation	Analytic	Simulation	Analytic
Gain (dB)	17.84	17.83	18.413	18.588
Gain	7.8	7.792	8.33	8.5
BW	1.695 MHz	1.917 MHz	3 MHz	3.0965 MHz
GBW	13.233 MHz	14.939 MHz	25 MHz	26.32 MHz
UGF	13.182 MHz	14.939 MHz	24.86 MHz	26.32 MHz

Comments:

- The cascode for bandwidth has slightly higher gain than CS
- It has better Bandwidth than CS as well as higher GBW as well as higher UGF
- The higher bandwidth is due to the severe reduction of the miller effect in this configuration
- Overall better performance than the CS Amplifier